

# MP04HB910

# **Dual Rectifier Diode Module**

**Preliminary Information** 

DS5425-1.2 February 2001

### **FEATURES**

- Dual Device Module
- Electrically Isolated Package
- **Pressure Contact Construction**
- International Standard Footprint
- Alumina (Non-toxic) Isolation Medium

#### **APPLICATIONS**

- Power Supplies
- Large IGBT Circuit 'Front Ends'
- Rectifiers
- Battery Chargers

### **VOLTAGE RATINGS**

Type Number	Repetitive Peak Voltages V <sub>DRM</sub> V <sub>RRM</sub> V	Conditions
MP04HB910-30 MP04HB910-28 MP04HB910-26 MP04HB910-24	3000 2800 2600 2400	$T_{vj} = -40^{\circ} \text{ to } 150^{\circ}\text{C},$ $V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available

### **ORDERING INFORMATION**

Order As:

#### MP04HB910-XX

XX shown in the part number about represents  $V_{\text{RRM}}/100$ selection required.

Note: When ordering, please use the complete part number. Please quote full part number in all correspondance.

### **KEY PARAMETERS**

$V_{RRM}$	3000V
I <sub>F(AV)</sub>	915A
FSM (per arm)	20000A
F(RMS)	1440A
V <sub>isol</sub>	3000V
1501	

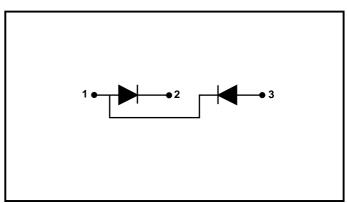


Fig.1 HB circuit configuration

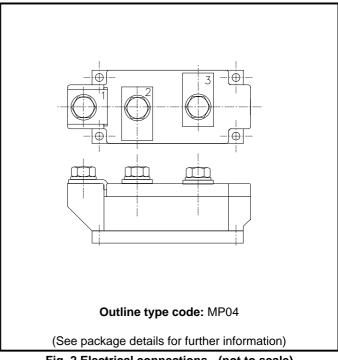


Fig. 2 Electrical connections - (not to scale)



# **ABSOLUTE MAXIMUM RATINGS - PER ARM**

Stresses above those listed under 'Absolute Maximum Ratings' may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability.

Symbol	Parameter	Conditions		Max.	Units
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	T <sub>case</sub> = 75°C	915	Α
			T <sub>case</sub> = 85°C	830	Α
			T <sub>case</sub> = 100°C	695	Α
I <sub>F(RMS)</sub>	RMS value	$T_{case} = 75^{\circ}C$		1440	Α
		$T_{\text{case}} = 85^{\circ}\text{C}$		1305	Α
		T <sub>case</sub> = 100°C		1090	Α
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; T <sub>j</sub> = 150°C		20	kA
l²t	I <sup>2</sup> t for fusing	$V_R = 0$		2.0 x 10 <sup>6</sup>	A²s
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; T <sub>j</sub> = 150°C		16	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 50\% V_{RRM}$		1.28 x 10 <sup>6</sup>	A <sup>2</sup> s
V <sub>isol</sub>	Isolation voltage	Commoned terminals to base plate AC RMS, 1 min, 50Hz		3000	V

### THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions	Min.	Max.	Units
$R_{th(j-c)}$	R <sub>th(j-c)</sub> Thermal resistance - junction to case (per diode)	dc	-	0.056	°C/W
		Halfwave	-	0.060	°C/W
		3 Phase	-	0.066	°C/W
T <sub>vj</sub>	Virtual junction temperature	Reverse (blocking)	-	150	°C
T <sub>stg</sub>	Storage temperature range	-	-40	150	°C
-	Screw torque	Mounting	6 (53)	-	Nm (lb.ins)
		Electrical connections	-	12 (106)	Nm (lb.ins)
-	Weight (nominal)	-	-	1580	g

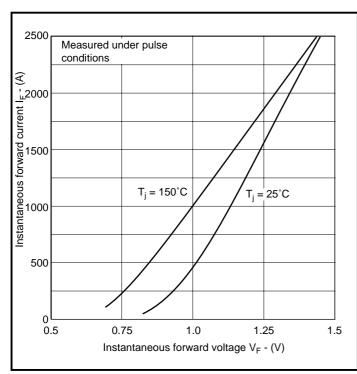


### **CHARACTERISTICS**

Symbol	Parameter	Conditions	Min.	Max.	Units
I <sub>RRM</sub>	Peak reverse current	At V <sub>RRM</sub> , T <sub>case</sub> = 150°C	-	50	mA
Q <sub>s</sub>	Total stored charge	$I_F = 1000A$ , $dI_{RR}/dt = 3A/\mu s$	-	1600	μС
I <sub>RR</sub>	Peak recovery current	$T_{\text{case}} = 150^{\circ}\text{C}, V_{R} = 100\text{V}$	-	85	Α
$V_{TO}$	Threshold voltage. See Note 1.	At $T_{v_j} = 150^{\circ}C$	-	0.7	V
r <sub>T</sub>	Slope resistance. See Note 1.	At $T_{v_j} = 150^{\circ}C$	-	0.29	mΩ

Note 1: The data given in this datasheet with regard to forward voltage drop is the for the calculation of the power dissipation in the semiconductor elements only. Forward voltage drops measured at the power terminals will be in excess of these figures due to the impedance of the busbars from the terminals to the semiconductor.

### **CURVES**



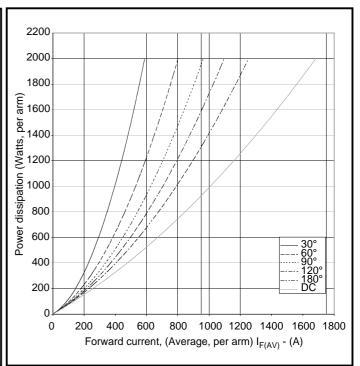
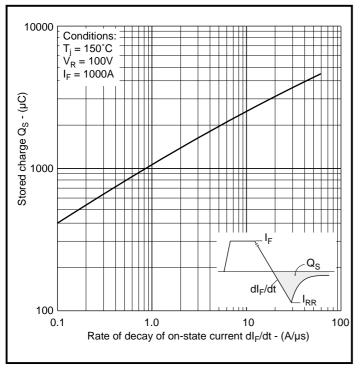


Fig.3 Maximum (limit) forward characteristics

Fig.4 Power dissipation curves





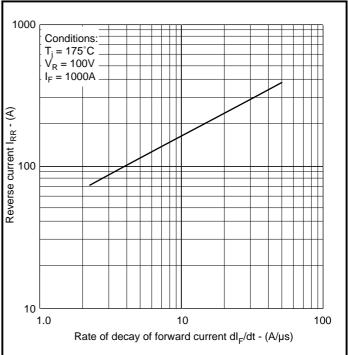


Fig.5 Maximum stored charge

Fig.6 Maximum reverse recovery current

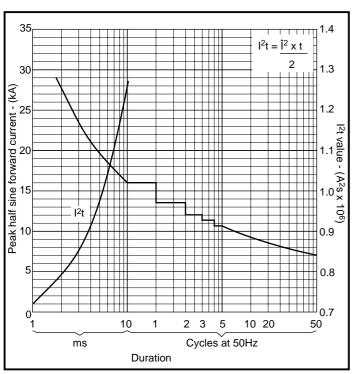


Fig.7 Surge (non-repetitive) forward current vs time (with 50%  $V_{RRM}$  @  $T_c$  - 150°C)

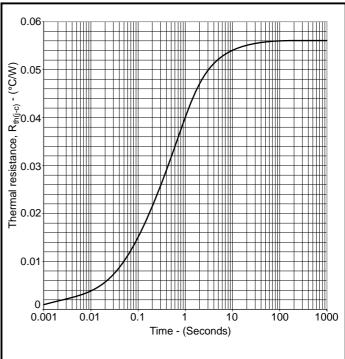


Fig.8 Transient thermal impedance - dc



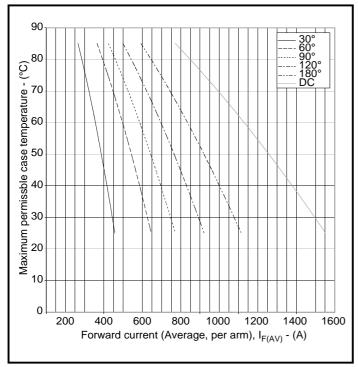
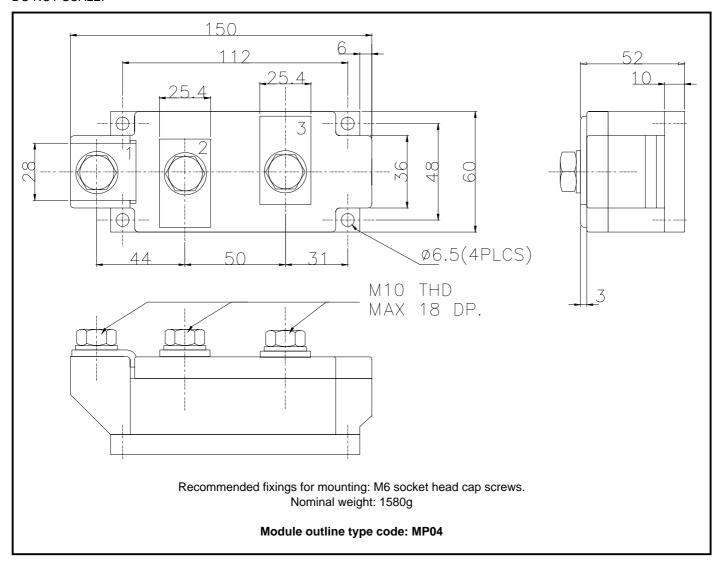


Fig.9 Maximum permissible case temperature vs forward current per arm at various conduction angles, 50/60Hz



# **PACKAGE DETAILS**

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





#### **POWER ASSEMBLY CAPABILITY**

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

### **HEATSINKS**

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks. They have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or customer service office.



#### http://www.dynexsemi.com

e-mail: power\_solutions@dynexsemi.com

HEADQUARTERS OPERATIONS
DYNEX SEMICONDUCTOR LTD

Doddington Road, Lincoln. Lincolnshire. LN6 3LF. United Kingdom. Tel: 00-44-(0)1522-500500 Fax: 00-44-(0)1522-500550

### DYNEX POWER INC.

99 Bank Street, Suite 410, Ottawa, Ontario, Canada, K1P 6B9 Tel: 613.723.7035 Fax: 613.723.1518

Toll Free: 1.888.33.DYNEX (39639)

CUSTOMER SERVICE CENTRES

Central Europe Tel: +33 (0)1 58 04 91 00. Fax: +33 (0)1 46 38 51 33 North America Tel: 011-800-5554-5554. Fax: 011-800-5444-5444

UK, Scandinavia & Rest Of World Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500020

SALES OFFICES

Central Europe Tel: +33 (0)1 58 04 91 00. Fax: +33 (0)1 46 38 51 33

North America Tel: (613) 723-7035. Fax: (613) 723-1518. Toll Free: 1.888.33.DYNEX (39639) /

Tel: (949) 733-3005. Fax: (949) 733-2986.

UK, Scandinavia & Rest Of World Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500020

These offices are supported by Representatives and Distributors in many countries world-wide.

© Dynex Semiconductor 2001 Publication No. DS5425-1 Issue No. 1.2 February 2001 TECHNICAL DOCUMENTATION – NOT FOR RESALE. PRINTED IN UNITED KINGDOM

#### Datasheet Annotations:

Dynex Semiconductor annotate datasheets in the top right hard corner of the front page, to indicate product status. The annotations are as follows:-

Target Information: This is the most tentative form of information and represents a very preliminary specification. No actual design work on the product has been started.

Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

Advance Information: The product design is complete and final characterisation for volume production is well in hand.

**No Annotation:** The product parameters are fixed and the product is available to datasheet specification.

This publication is issued to provide information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. The Company reserves the right to alter without prior notice the specification, design or price of any product or service. Information concerning possible methods of use is provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the user's responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to the Company's conditions of sale, which are available on request.

All brand names and product names used in this publication are trademarks, registered trademarks or trade names of their respective owners.